

Data sheet acquired from Harris Semiconductor SCHS082C - Revised October 2003

# **CMOS 8-Bit Priority Encoder**

High-Voltage Types (20-Volt Rating)

■ CD4532B consists of combinational logic that encodes the highest priority input (D7-D0) to a 3-bit binary code. The eight inputs, D7 through D0, each have an assigned priority; D7 is the highest priority and D0 is the lowest. The priority encoder is inhibited when the chip-enable input Ei is low. When E<sub>1</sub> is high, the binary representation of the highest-priority input appears on output lines Q2-Q0, and the group select line GS is high to indicate that priority inputs are present. The enable-out (E<sub>O</sub>) is high when no priority inputs are present. If any one input is high, EO is low and all cascaded lower-order stages are disabled.

The CD4532B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, MT, and NSR suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

#### Features:

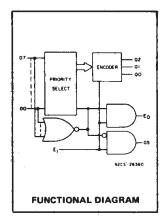
- Converts from 1 of 8 to binary
- Provides cascading feature to handle any number of inputs
- Group select indicates one or more priority inputs
- Standardized, symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 µA at 18 V over full package temperature range; 100 nA at 18 V and 25°C
- Noise margin (full-package-temperature range):

0.5 V at V<sub>DD</sub> = 5 V 1.5 V at V<sub>DD</sub> = 10 V 1.5 V at V<sub>DD</sub> = 15 V

- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

#### Applications:

- Priority encoder
- Binary or BCD encoder (keyboard encoding)
- Floating point arithmetic



CD4532B Types

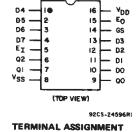
#### **RECOMMENDED OPERATING CONDITIONS**

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

Characteristic	Min.	Max	Units
Supply Voltage Range (for T <sub>A</sub> =	3	18	V
Full Package Temp. Range)			

#### MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (VDD) INPUT VOLTAGE RANGE, ALL INPUTS .....-0.5V to VDD +0.5V POWER DISSIPATION PER PACKAGE (PD): For T<sub>A</sub> = +100°C to +125°C ...... Derate Linearity at 12mW/°C to 200mW DEVICE DISSIPATION PER OUTPUT TRANSISTOR FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)........... 100mW OPERATING-TEMPERATURE RANGE (TA) .....-55°C to +125°C STORAGE TEMPERATURE RANGE (Tstg) .....-65°C to +150°C LEAD TEMPERATURE (DURING SOLDERING): 



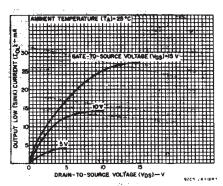


Fig. 1 — Typical output low (sink) current

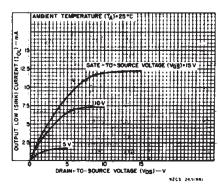


Fig. 2 - Minimum output low (sink) current characteristics.

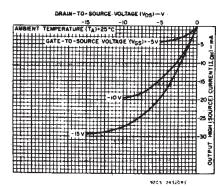


Fig. 3 — Typical output high (source) current characteristics.

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#### STATIC ELECTRICAL CHARACTERISTICS

CHARACTER-	CONE	OITION	ıs	LIMI	TS AT	INDICA	TED TE	MPER/	ATURES	(°C)	UNITS	
ISTIC	Vo	VIN	VDD						+25		0,4113	
	(V)	(V)	(V)	-55	<del>-4</del> 0	+85	+125	Min.	Тур.	Max.		
Quiescent Device		0,5	5	5	5	150	150	-	0.04	5		
Current,		0,10	10	10	10	300	300	-	0.04	10	μА	
IDD Max.	_	0,15	15	20	20	600	600	-	0.04	20	μ~	
		0,20	20	100	100	3000	3000	_	0.08	100		
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	-		
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6		* *	
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	_		
Output High	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	_	mA	
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	-		
Current, IOH Min.	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	- <del>-</del> -		
TOH WATER	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8			
Output Voltage:	_	0,5	5		0	.05		_	0	0.05		
Low-Level, VOL Max.	-	0,10	10		0	.05			0	0.05		
VUL Max.	-	0,15	15		0	.05		-	0	0.05	l v	
Output Voltage:		0,5	5		4	.95		4.95	5	-	ľ	
High-Level,	. –	0,10	10		9	95		9.95	10			
VOH Min.	_	0,15	15		14	1.95		14.95	15			
Input Low	0.5, 4.5	1	5			1		-		1.5		
Voltage, VIL Max.*	1, 9	-	10		2	.5		-	_	3		
VIL Max.	1.5,13.5	_	15			3		_		4	v	
Input High	0.5, 4.5	_	5			4		3.5			ľ	
Voltage,	1, 9	-	10		7	.5		7				
VIH Min.	1.5,13.5	_	15		1	2		11	_	_		
Input Current IIN Max.		0,18	18	±0.1	±0.1	±1	±1	_	±10 <sup>-5</sup>	±0.1	μΑ	

<sup>\*</sup>One input is tested at a time; other inputs should be at  $V_{DD}$  or  $V_{SS}$ . For testing all inputs at  $V_{IL}$  and  $V_{IH}$  levels, use 20%/80%  $V_{DD}$ .

# DYNAMIC ELECTRICAL CHARACTERISTICS at T\_A=25°C; C\_L=50 pF, Input t\_r,t\_f= 20 ns, R\_L=200 K $\Omega$

CHARACTERISTIC	TEST CONDITIONS VDD	LIF	UNITS	
	VOLTS	TYP.	MAX.	1
Propagation Delay Time tpHL, tpLH	5	110	220	
E <sub>I</sub> to E <sub>O</sub> , E <sub>I</sub> to GS	10	55	110	
	15	45	85	1
	5	170	340	1
Et to Qm, Dn to GS	10	85	170	ns
	15	65	125	1
	5	220	440	
Dn to Q <sub>M</sub>	10	110	220	
	15	85	160	[
	5	100	200	
Transition Time tTHL, tTLH	10	50	100	ns
	15	40	80	
Input Capacitance CIN	Any Input	5	7.5	pF

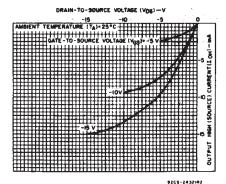


Fig. 4 — Minimum output high (source) current characteristics.

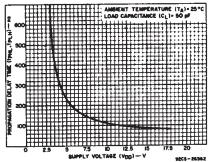


Fig. 5 — Typical propagation delay (Dn to Qm) vs. supply voltage.

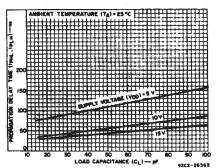


Fig. 6 — Typical propagation delay (E<sub>1</sub> to GS, E<sub>1</sub> to E<sub>O</sub>) vs. load capacitance.

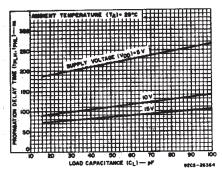


Fig. 7 — Typical propagation delay (Dn to Qm) vs. load capacitance.

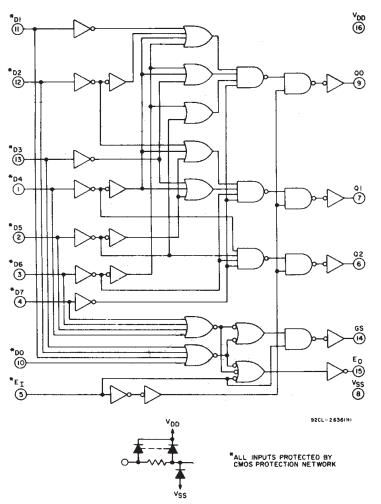


Fig. 8 — CD4532 logic diagram.

#### TRUTH TABLE

			,	Input		Output							
ΕĮ	D7	D6	D5	D4	D3	D2	D1	D0	GS	Q2	Q1	Q0	Eo
0	Х	Х	Х	Х	Х	X.	Х	X	Ō	0	0	0	0
1	0	0	0	0	0	0	0	0	0	0	0	0	1
1	1	Χ.	х	Х	Х	Х	×	Х	1	1	1	1	0
1	0	1	Х	х	х	Х	X	Х	1	1	1	0	0
1	0	0	1	Х	×	Х	×	х	1	1	0	1	0
1	0	0	0	1	×	Х	x	Х	1	1	0	0	0
1	0	0	0	0	1	Х	Х	Х	1	0	1	1	0
1	0	0	0	0	0	1	×	х	1	0	1	0	0
1	0	0	0	0	0	0	1	х	1	0	0	1	0
1	0	0	0	0	0	0	0	1	1	0	0	0	0

X = Don't Care Logic 1  $\equiv$  High Logic 0  $\equiv$  Low

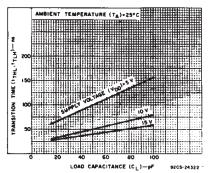


Fig.9 – Typical transition time vs. load capacitance.

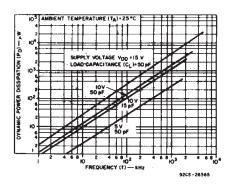


Fig. 10 — Typical dynamic power dissipation vs. fraquency.

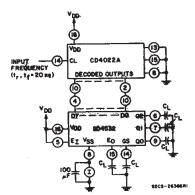


Fig.11 — Dynamic power dissipation test circuit.

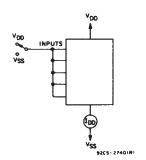


Fig. 12 - Quiescent device current test circuit.

## CD4532B Types

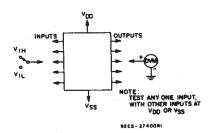


Fig. 13 - Input voltage test circuit.

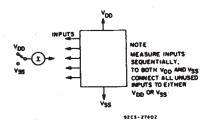
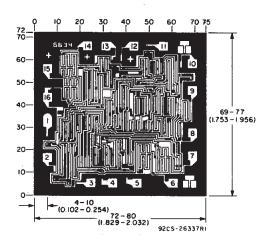


Fig. 14 - Input current test circuit.



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils  $(10^{-3})$  inch).

Dimensions and pad layout for CD4532BH.

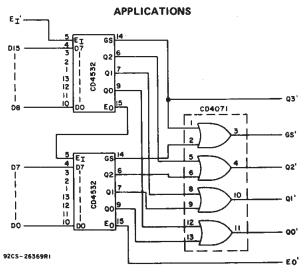
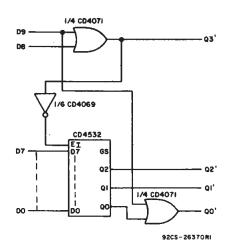


Fig. 15 - 16-level priority encoder.



TRUTH TABLE

ſ					In	out							Qui	tput	
ſ	D9	D8	D7	D6	<b>D</b> 5	D4	D3	D2	D1	DO	GS	σ3.	Q2'	01'	GO,
ſ	1	х	х	х	х	Х	х	х	Х	х	0	1	0	0	1
ı	0	1	x	X	Х	×	X	Х	Х	X	0	1	0	0	0
ľ	0	0	1	х	Х	Х	Х	Х	X	X	1-	0	1	1	1
1	0	0	0	1 -	x	х	X	X.	X	х	1	0	1	1	0
1	0	0	0	0	1	X	X	X	Х	Х	1	0	1	0	1
ı	0	0	0	0	0	_1_	X	X	Х	Х	1 1	0	1	0	0
I	0	0	0	0	0	0	1	Х	Х	Х	1	0.	0	1	1
ł	0	0	0	0	0	0	0	1	Х	х	1	- 0	0	1	0
١	0	0	0	0	0	0	0	0	1	х	1	0	0	0	1
ı	0	0	0	0	0	0	0	0	0	1	1	0	0	0	0
	X =	Don	't Ca	re			Logic 1 ≡ High					Logic 0 ≡ Low			

Fig.16 - 0-to-9 keyboard encoder.

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#### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD4532BE	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4532BE	Samples
CD4532BEE4	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4532BE	Samples
CD4532BF3A	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4532BF3A	Samples
CD4532BM96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4532BM	Samples
CD4532BNSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4532B	Samples
CD4532BPWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM532B	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

# **PACKAGE OPTION ADDENDUM**

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#### OTHER QUALIFIED VERSIONS OF CD4532B, CD4532B-MIL:

Military: CD4532B-MIL

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

• Military - QML certified for Military and Defense Applications

# **PACKAGE MATERIALS INFORMATION**

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### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4532BM9	6 SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4532BNS	R SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4532BPW	R TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4532BM96	SOIC	D	16	2500	340.5	336.1	32.0
CD4532BNSR	SO	NS	16	2000	356.0	356.0	35.0
CD4532BPWR	TSSOP	PW	16	2000	356.0	356.0	35.0

# **PACKAGE MATERIALS INFORMATION**

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### **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD4532BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4532BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4532BEE4	N	PDIP	16	25	506	13.97	11230	4.32
CD4532BEE4	N	PDIP	16	25	506	13.97	11230	4.32



SOP



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



SOF



### NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOF



#### NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



# D (R-PDS0-G16)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## **MECHANICAL DATA**

# NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

### PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



# 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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